



General Description

The WSR80N08 is the highest performance trench N-ch MOSFET with extreme high cell density,which provide excellent R_{DSON} and gate charge for most of the synchronous buck converter applications .

The WSR80N08 meet the RoHS and Green Product requirement,100% EAS guaranteed with full function reliability approved.

Features

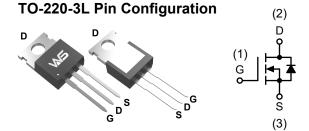
- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

Product Summery

BV _{DSS}	R _{DSON}	I _D	
80V	8.4mΩ	80A	

Applications

- Power Management
- DC/DC Converter
- Load Switch



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage 80		V
V_{GS}	Gate-Source Voltage	±20	V
I _D	T _C = 25°Continuous Drain Current. Lead current limit.	80	Α
I _{DM}	T_C = 25°C,pulse width limited by T_{JM}	75	Α
I _{AR}	T _C = 25°C,Avalanche Current.	320	А
E _{AR}	TC = 25°C,Single Pulse Avalanche Energy ³	30	mJ
E _{AS}	TC = 25°C,Single Pulse Avalanche Energy ³	1.0	J
P _D	TC = 25°C,Total Power Dissipation ⁴	230	W
TJ	Operating Junction Temperature Range	-55 to 175	$^{\circ}$
T _{JM}	Storage Temperature Range	-55 to 175	$^{\circ}$
TJ	MAX Junction Temperature Range	175	$^{\circ}$
R _{θJA}	Thermal Resistance Junction-Ambient ¹	62	°C/W
R _{eJC}	Thermal Resistance Junction-Case ¹	0.65	°C/W





Electrical Characteristics (TJ=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	80			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25℃ , I _D =1mA		0.096		V/°C	
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V,I _D =40A.		8.4	9.5	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	\/ -\/ -2500A	2.0	3	4.0	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	$V_{GS}=V_{DS}$, $I_D=250uA$		-5.5		mV/℃	
,	Drain-Source Leakage Current	V _{DS} =55V , V _{GS} =0V , T _J =25℃			50		
I _{DSS}		V_{DS} =55 V , V_{GS} =0 V , T_{J} =85 $^{\circ}$ C			1000	· uA	
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20 V$, V_{DS} = $0 V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =10V , I _D =40A	35	55		S	
R_g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.8	3.8	Ω	
Qg	Total Gate Charge (10V)			180			
Q _{gs}	Gate-Source Charge	V _{DS} =60V,V _{GS} =10V,I _D =40A		42		nC	
Q _{gd}	Gate-Drain Charge			75			
T _{d(on)}	Turn-On Delay Time			50			
Tr	Rise Time	V _{DS} =60V, V _{GS} =10V ,		75			
T _{d(off)}	Turn-Off Delay Time	$R_G=2.5\Omega$, $I_D=40A$.		31		ns	
T _f	Fall Time			95			
C _{iss}	Input Capacitance			4800			
Coss	Output Capacitance	V _{DS} =25V , V _{GS} =0V , f=1MHz		1670		pF	
C _{rss}	Reverse Transfer Capacitance			590			

Diode Characteristics(T_J = 25°C, unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _S	Continuous Source Current ^{1,6}	V _{GS} =0V,			80	Α
I _{SM}	Pulsed Source Current ^{2,6}	pulse width limited by T _{JM}			320	Α
V_{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =I _F . Note2			1.5	V
t _{rr}	Reverse Recovery Time	- I _ε =25A _. d _i /d _i =100A/μs.		200		nS
Q _{rr}	Reverse Recovery Charge	1;-20π,αβα <u>t</u> -100π/μ3.		500		nC

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper,t<=10sec.
- 2. The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3. The EAS data shows Max. rating . The test condition is V_{DS} =25V, V_{GS} =10V,L=0.1mH,I_{AS}=25A
- 4. The power dissipation is limited by 150 $^{\circ}\mathrm{C}^{\,}$ junction temperature
- 5. The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

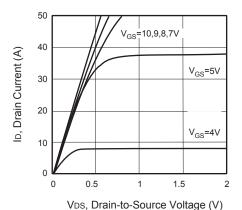


Figure 1. Output Characteristics

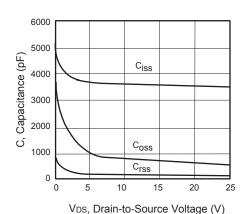


Figure 3. Capacitance

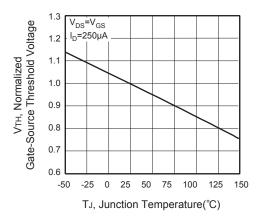


Figure 5. Gate Threshold Variation with Temperature

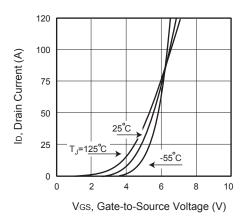


Figure 2. Transfer Characteristics

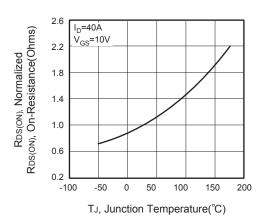


Figure 4. On-Resistance Variation with Temperature

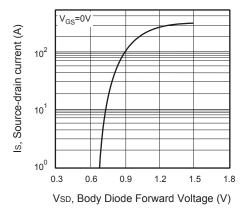


Figure 6. Body Diode Forward Voltage Variation with Source Current



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

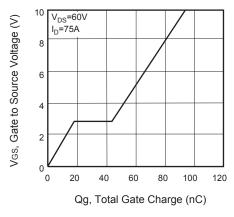


Figure 7. Gate Charge

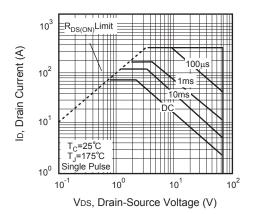


Figure 8. Maximum Safe Operating Area

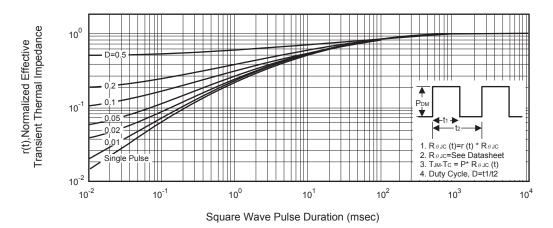
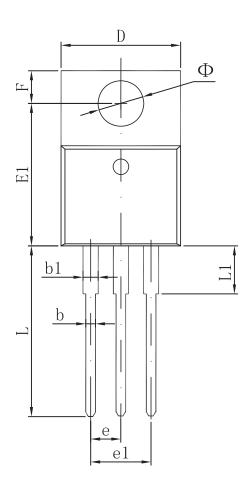
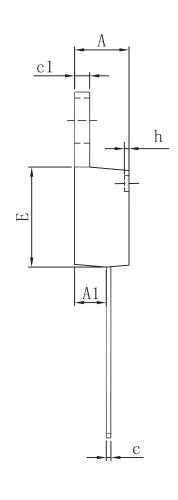


Figure 9. Normalized Thermal Transient Impedance Curve



Packaging information





Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	4.470	4.670	0.176	0.184	
A1	2. 520	2.820	0.099	0.111	
b	0.710	0.910	0.028	0.036	
b1	1. 170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
Е	8. 500	8.900	0.335	0.350	
E1	12.060	12.460	0.475	0.491	
е	2.540	2.540 TYP) TYP	
e1	4. 980	5. 180	0.196	0.204	
F	2. 590	2.890	0.102	0.114	
h	0.000	0.300	0.000	0.012	
L	13.400	13.800	0. 528	0.543	
L1	3. 560	3.960	0.140	0.156	
Ф	3. 735	3.935	0.147	0.155	



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